

PATENT ASSIGNMENT COVER SHEET

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
CHAO-CHING CHENG	11/14/2011
CHIH-HSIN KO	11/14/2011
HSINGJEN WANN	11/16/2011
RECEIVING PARTY DATA	
Name:	TAIWAN SEMICONDUCTOR MANUFACTURING COMPANY, LTD.
Street Address:	NO. 8, LI-HSIN RD. 6
Internal Address:	SCIENCE-BASED INDUSTRIAL PARK
City:	HSIN-CHU
State/Country:	TAIWAN
Postal Code:	300-77
PROPERTY NUMBERS Total: 1	
Property Type	Number
Application Number:	16678045
CORRESPONDENCE DATA	
Fax Number:	(214)200-0853
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
Phone:	2146515000
Email:	ipdocketing@haynesboone.com
Correspondent Name:	HAYNES AND BOONE, LLP IP SECTION
Address Line 1:	2323 VICTORY AVENUE
Address Line 2:	SUITE 700
Address Line 4:	DALLAS, TEXAS 75219
ATTORNEY DOCKET NUMBER:	2011-0802/24061.1953US03
NAME OF SUBMITTER:	KYLE HOWARD
SIGNATURE:	/Kyle Howard/
DATE SIGNED:	11/08/2019
Total Attachments: 2	
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ASSIGNMENT

WHEREAS, we,

- (1) Chao-Ching Cheng of No. 30, Lane 166, Xinzhuang Street, East District Hsinchu City 300, Taiwan, R.O.C.
- (2) Chih-Hsin Ko of No. 1, Lane 200, Wunheng Road Fongshan City, Kaohsiung County 830, Taiwan, R.O.C.
- (3) Hsingjen Wann of 1179 Barrett Circle West Carmel, NY 10512, U.S.A.

have invented certain improvements in

(110) SURFACE ORIENTATION FOR REDUCING FERMI-LEVEL-PINNING BETWEEN HIGH-K DIELECTRIC AND GROUP III-V COMPOUND SEMICONDUCTOR SUBSTRATE

for which we have filed and executed an application for Letters Patent of the United States of America on Nov. 18, 2011, as U.S. Serial No. 13/299,529; and

WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

WHEREAS, Taiwan Semiconductor Manufacturing Company, Ltd., ("TSMC"), No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park Hsin-Chu, Taiwan 300-77, Republic of China, is desirous of obtaining the entire right, title, and interest in, to and under the said invention and the said application in the United States of America and in any and all countries foreign thereto;

NOW, THEREFORE, good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, and other good and valuable consideration, we have sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said TSMC, its successors, legal representatives, and assigns, the entire right, title, and interest in, to and under the said invention, and the said application, and all divisional, renewal, substitutional, and continuing applications thereof, and all Letters Patent of the United States of America which may be granted thereon and all reissues and extensions thereof, and all applications for Letters Patent which may be filed for said invention in any country or countries foreign to the United States of America, and all extensions, renewals, and reissues thereof, and all prior patents and patent applications from which a filing priority of the above-described patent application may be obtained, including the right to collect past damages; and we hereby authorize and request the Commissioner of Patents of the United States of America, and any official of any country or countries foreign to the United States of America, whose duty it is to issue patents on applications as aforesaid, to issue all Letters Patent for said invention to the said TSMC, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

Docket No.: 2011-0802 / 24061.1953

Customer No.: 42717

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional, continuing, and reissue applications, make all rightful declarations and/or oaths and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Inventor Name: Chao-Ching Cheng

Residence Address: No. 30, Lane 166, Xinzhuang Street, East District
Hsinchu City 300, Taiwan, R.O.C.

Dated: 2011.11.14

Chao-Ching Cheng
Inventor Signature

Inventor Name: Chih-Hsin Ko

Residence Address: No. 1, Lane 200, Wunheng Road
Fongshan City, Kaohsiung County 830, Taiwan, R.O.C.

Dated: 2011.11.14

Chih-Hsin Ko
Inventor Signature

Inventor Name: Hsingjen Wann

Residence Address: 1179 Barrett Circle West
Carmel, NY 10512, U.S.A.

Dated: 11/16/2011

Hsingjen Wann
Inventor Signature